SILICON POWER TRANSISTOR 2SC4551

NPN SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SC4551 is a power transistor developed for high-speed switching and features low $V_{CE(sat)}$ and high hFE. This transistor is ideal for use in drivers such as DC/DC converters and actuators.

In addition, a small resin-molded insulation type package contributes to high-density mounting and reduction of mounting cost.

FEATURES

NEC

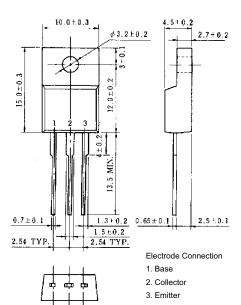
- High hFE and low VCE(sat): hFE \geq 100 (VCE = 2 V, IC = 2 A) VCE(sat) \leq 0.3 V (IC = 6 A, IB = 0.3 A)
- Mold package that does not require an insulating board or insulation bushing

| n | | |
|----------------|--|--|
| Symbol | Ratings | Unit |
| Vсво | 100 | V |
| VCEO | 60 | V |
| Vebo | 7.0 | V |
| IC(DC) | 10 | А |
| IC(pulse)* | 20 | А |
| B(DC) | 5.0 | А |
| P⊤ (Tc = 25°C) | 30 | W |
| P⊤ (Ta = 25°C) | 2.0 | W |
| Tj | 150 | °C |
| Tstg | –55 to +150 | °C |
| | VCBO VCEO VEBO IC(DC) IC(pulse)* IB(DC) PT (Tc = 25°C) PT (Ta = 25°C) Tj | VCBO 100 VCEO 60 VEBO 7.0 Ic(DC) 10 Ic(pulse)* 20 IB(DC) 5.0 PT (Tc = 25°C) 30 PT (Ta = 25°C) 2.0 T _j 150 |

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

* PW \leq 300 μ s, duty cycle \leq 10%

PACKAGE DRAWING (UNIT: mm)



The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

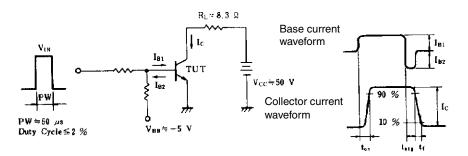
| Parameter | Symbol | Conditions MIN. 1 | | TYP. | MAX. | Unit |
|------------------------------|-------------------------|---|-----|------|------|------|
| Collector to emitter voltage | VCEO(SUS) | Ic = 6.0 A, I _B = 0.6 A, L = 1 mH | 60 | | | V |
| Collector to emitter voltage | VCEX(SUS) | Ic = 6.0 A, I _{B1} = $-I_{B2}$ = 0.6 A, V _{BE(OFF)} = -1.5 V, L = 180 μ H, clamped | 60 | | | V |
| Collector cutoff current | Ісво | $V_{CB} = 60 \text{ V}, \text{ I}_{E} = 0$ | | | 10 | μA |
| Collector cutoff current | ICER | Vce = 60 V, R _{BE} = 50 Ω, Ta = 125°C | | | 1.0 | mA |
| Collector cutoff current | ICEX1 | $V_{CE} = 60 \text{ V}, \text{ V}_{BE(OFF)} = -1.5 \text{ V}$ | | | 10 | μΑ |
| Collector cutoff current | ICEX2 | $V_{CE} = 60 \text{ V}, V_{BE(OFF)} = -1.5 \text{ V},$ Ta = 125°C | | | 1.0 | mA |
| Emitter cutoff current | Іево | V _{EB} = 5.0 V, Ic = 0 | | | 10 | μA |
| DC current gain | hfe1* | Vce = 2.0 V, Ic = 1.0 A | 100 | | | |
| DC current gain | hFE2* | Vce = 2.0 V, Ic = 2.0 A | 100 | 200 | 400 | |
| DC current gain | hfe3* | Vce = 2.0 V, Ic = 6.0 A | 60 | | | |
| Collector saturation voltage | V _{CE(sat)1} * | Ic = 6.0 A, I _B = 0.3 A | | | 0.3 | V |
| Collector saturation voltage | VCE(sat)2* | Ic = 8.0 A, I _B = 0.4 A | | | 0.5 | V |
| Base saturation voltage | V _{BE(sat)1} * | Ic = 6.0 A, I _B = 0.3 A | | | 1.2 | V |
| Base saturation voltage | VBE(sat)2* | Ic = 8.0 A, I _B = 0.4 A | | | 1.5 | V |
| Collector capacitance | Cob | V _{CB} = 10 V, I _E = 0, f = 1.0 MHz | | 150 | | pF |
| Gain bandwidth product | f⊤ | Vce = 10 V, Ic = 1.0 A | | 140 | | MHz |
| Turn-on time | ton | $I_{C} = 6.0 \text{ A}, \text{ R}_{L} = 8.3 \Omega,$ | | | 0.3 | μs |
| Storage time | tstg | I _{B1} = −I _{B2} = 0.3 A, Vcc ≅ 50 V Refer to the test circuit. | | | 1.5 | μs |
| Fall time | tr | | | | 0.3 | μs |

* Pulse test PW \leq 350 μ s, duty cycle \leq 2%

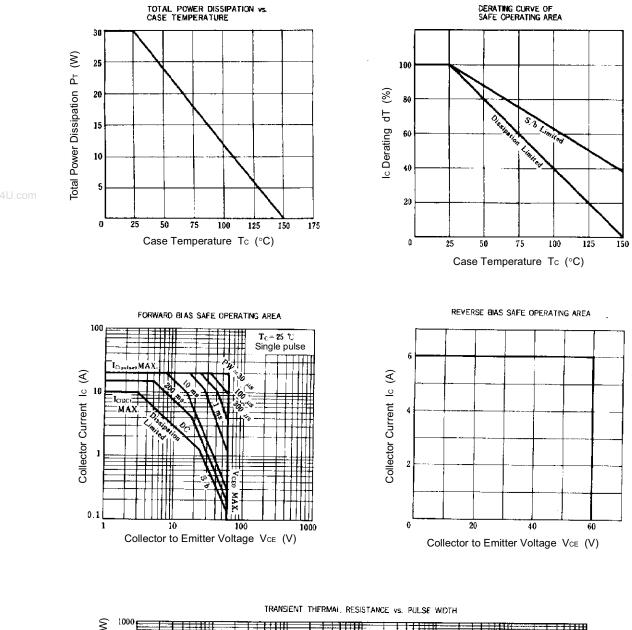
hfe CLASSIFICATION

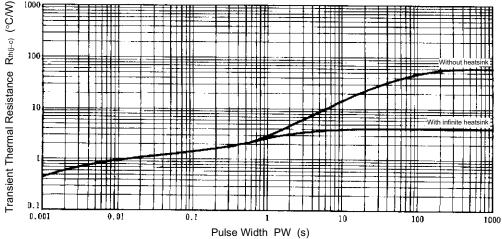
| Marking | М | L | к |
|---------|------------|------------|------------|
| hFE2 | 100 to 200 | 150 to 300 | 200 to 400 |

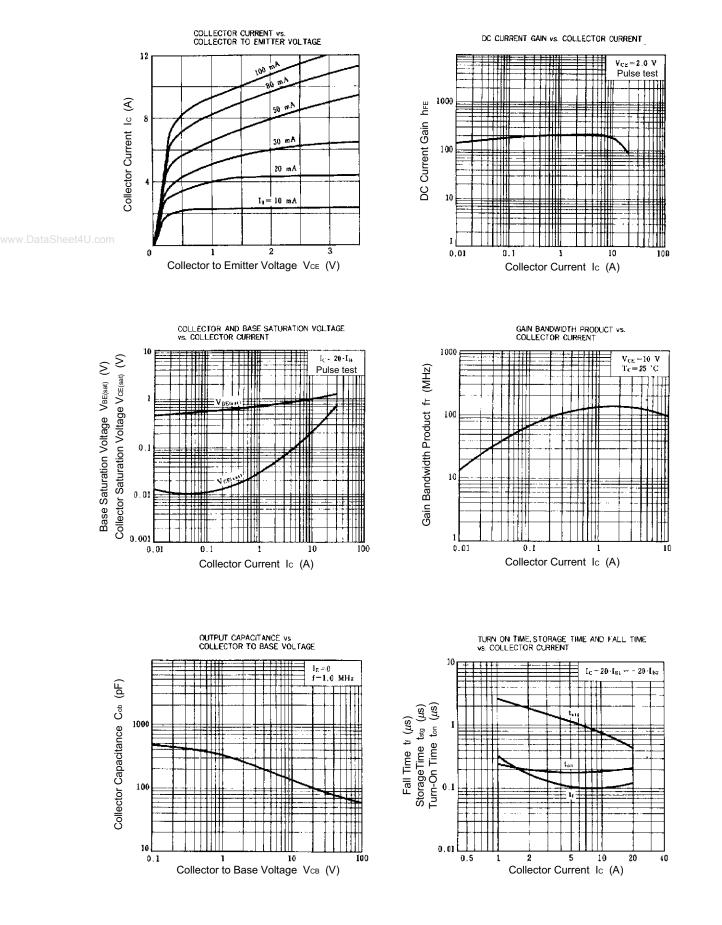
SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT



TYPICAL CHARACTERISTICS (Ta = 25°C)







[MEMO]

ww.DataSheet4U.com

- The information in this document is current as of July, 2001. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products and/or types are available in every country. Please check with an NEC sales representative for availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC semiconductor products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative
 purposes in semiconductor product operation and application examples. The incorporation of these
 circuits, software and information in the design of customer's equipment shall be done under the full
 responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third
 parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers
 agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize
 risks of damage to property or injury (including death) to persons arising from defects in NEC
 semiconductor products, customers must incorporate sufficient safety measures in their design, such as
 redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:
 "Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products
 developed based on a customer-designated "quality assurance program" for a specific application. The
 recommended applications of a semiconductor product depend on its quality grade, as indicated below.
 Customers must check the quality grade of each semiconductor product before using it in a particular
 application.
 - "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
 - "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
 - "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.

(Note)

- (1) "NEC" as used in this statement means NEC Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).